N-Channel 100 V (D-S) MOSFET

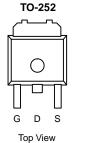
PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a			
100	0.0068 at V _{GS} = 10 V	90			
	0.0095 at V _{GS} = 4.5 V	80			

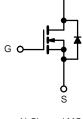
FEATURES

- 175 °C Junction Temperature
- TrenchFET[®] Power MOSFET

D

• Material categorization:





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted)						
Parameter	Symbol	Limit	Unit			
Gate-Source Voltage		V _{GS}	± 20	V		
Continuous Drain Current /T 175 °C\b	T _C = 25 °C	1_	90			
Continuous Drain Current (T _J = 175 °C) ^b	T _C = 100 °C	D	80 ^a			
Pulsed Drain Current	I _{DM}	330	A			
Continuous Source Current (Diode Conduction)	۱ _S	80 ^a				
Avalanche Current	I _{AS}	80	1			
Single Avalanche Energy (Duty Cycle \leq 1 %)	L = 0.1 mH	E _{AS}	125	mJ		
Maximum Dawar Dissinction	T _C = 25 °C	P _D	136	W		
Maximum Power Dissipation	T _A = 25 °C	FD FD	3 ^b , 8.3 ^{b, c}	7 ~ ~ ~		
Operating Junction and Storage Temperature Range	·	T _J , T _{stg}	- 55 to 175	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Mauiauna lunation ta Arabianta	$t \le 10 \text{ sec}$	- R _{thJA}	15	18	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		40	50		
Maximum Junction-to-Case		R _{thJC}	0.85	1.1		

Notes:

a. Package limited.

b. Surface mounted on 1" x 1" FR4 board.

c. t \leq 10 s.





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Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static					<u> </u>		
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$	100			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1	1 2 3		V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$		1			
	I _{DSS}	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 \text{ °C}$			50	μA	
		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 \text{ °C}$			250		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	90			А	
		V _{GS} = 10 V, I _D = 20 A		0.0068	0.0085		
	D	V_{GS} = 10 V, I _D = 20 A, T _J = 125 °C			0.0140		
Drain-Source On-State Resistance ^b	R _{DS(on)}	V_{GS} = 10 V, I_{D} = 20 A, T_{J} = 175 °C			0.0180	Ω	
		V _{GS} = 4.5 V, I _D = 15 A		0.0095	0.0120		
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		50		S	
Dynamic							
Input Capacitance	C _{iss}			4150		pF	
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz		420			
Reverse Transfer Capacitance	C _{rss}			35			
Total Gate Charge ^c	Qg			47	70	nC	
Gate-Source Charge ^c	Q _{gs}	$V_{\rm DS}$ = 30 V, $V_{\rm GS}$ = 10 V, $I_{\rm D}$ = 50 A		15			
Gate-Drain Charge ^c	Q _{gd}			10			
Turn-On Delay Time ^c	t _{d(on)}			10	20		
Rise Time ^c	t _r	$V_{DD} = 30 \text{ V}, \text{ R}_{L} = 0.6 \Omega$		10	20	ns	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 50$ A, V_{GEN} = 10 V, R_g = 2.5 Ω		35	50		
Fall Time ^c	t _f			6	10		
Source-Drain Diode Ratings and Cha	aracteristics (T _C = 25 °C)					
Pulsed Current	I _{SM}				320	Α	
Diode Forward Voltage	V_{SD}	$I_{F} = 20 \text{ A}, V_{GS} = 0 \text{ V}$		1	1.5	V	
Reverse Recovery Time	t _{rr}	I _F = 20 A, di/dt = 100 A/μs		85	110	ns	

Notes:

a. For design aid only; not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

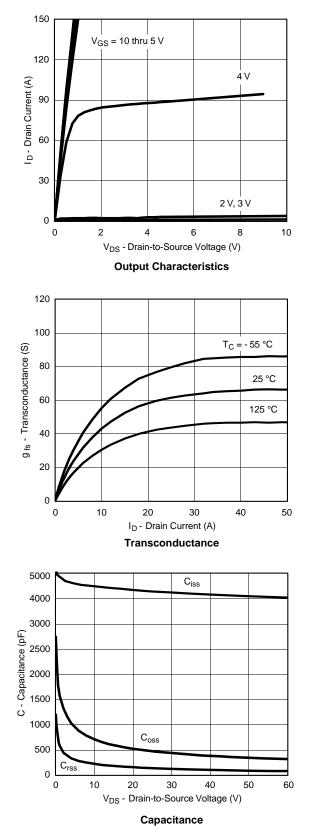
c. Independent of operating temperature.

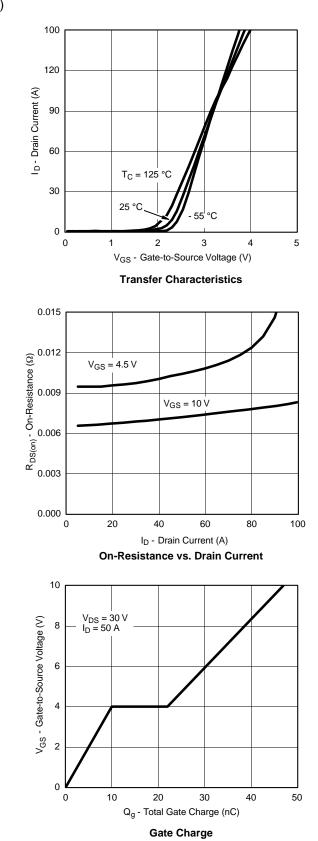
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS (25 °C unless noted)

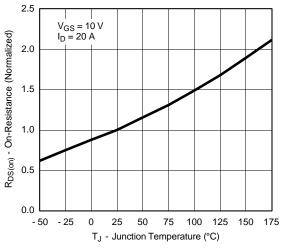




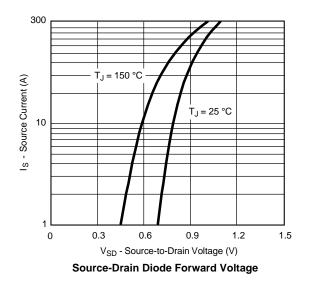


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TYPICAL CHARACTERISTICS (25 °C unless noted)



On-Resistance vs. Junction Temperature

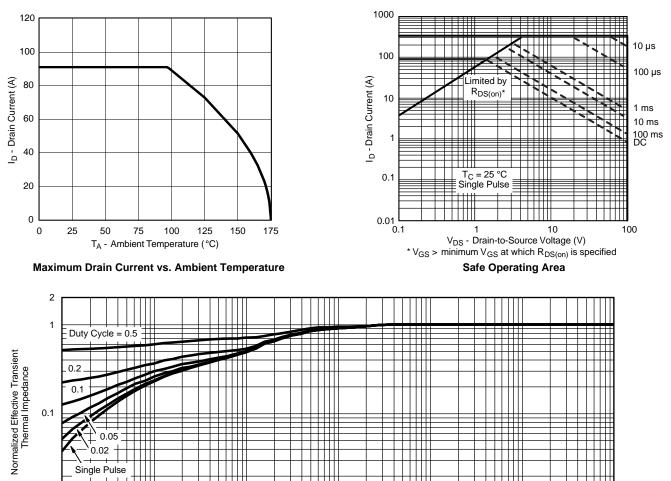


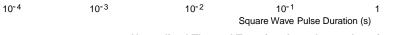


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THERMAL RATINGS





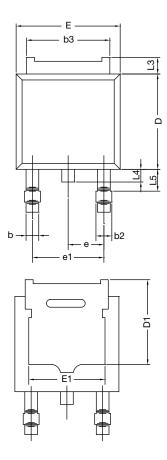
Normalized Thermal Transient Impedance, Junction-to-Case

10

100









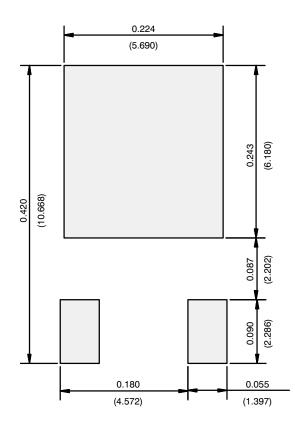
	MILLIN	IETERS	INC	HES		
DIM.	MIN.	MAX.	MIN.	MAX.		
А	2.18	2.38	0.086	0.094		
A1	-	0.127	-	0.005		
b	0.64	0.88	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215		
С	0.46	0.61	0.018	0.024		
C2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245		
D1	5.21	-	0.205	-		
Е	6.35	6.73	0.250	0.265		
E1	4.32	-	0.170	-		
Н	9.40	10.41	0.370	0.410		
е	2.28	BSC	0.090	BSC		
e1	4.56	4.56 BSC		0.180 BSC		
L	1.40	1.78	0.055	0.070		
L3	0.89	1.27	0.035	0.050		
L4	-	1.02	-	0.040		
L5	1.14	1.52	0.045	0.060		
ECN: X12-0247-Rev. M, 24-Dec-12 DWG: 5347						

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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